

35772 U.S. PTO

# BAKER BOTTS LLP

November 21, 2000

THE WARNER  
1299 PENNSYLVANIA AVE , NW  
WASHINGTON, DC  
20004-2400  
202 639 7700  
FAX 202 639.7890

AUSTIN  
BAKU  
DALLAS  
HOUSTON  
LONDON  
MOSCOW  
NEW YORK  
WASHINGTON

## UTILITY PATENT APPLICATION TRANSMITTAL

Attorney Docket Number: 004578.1106  
First Named Inventor: Gary FRAZIER  
Title: SUPER-REGENERATIVE MICROWAVE DETECTOR

TO: **BOX PATENT APPLICATION**  
Commissioner for Patents  
Washington, D.C. 20231

Sir:

Attached are the following for filing with the U.S. Patent and Trademark Office:

1. ☒ Fee Transmittal Form (original and duplicate)
2. ☒ Specification - Total Pages: 15 (Including Abstract)

CLAIMS AS FILED						
	Claims Filed	Basic Fee Claims	Extra	Rate		Amount
				Large Entity	Small Entity	
Total Claims	24	20	4	\$ 18.00	\$ 9.00	\$ 72.00
Independent Claims	4	3	1	\$ 80.00	\$ 40.00	\$ 80.00
First Presentation of Multiple Dependent Claims				\$ 270.00	\$ 135.00	\$ 0.00
<b>BASIC FEE</b>				\$ 710.00	\$ 355.00	\$ 710.00
<b>TOTAL FILING FEE</b>						\$ 862.00

3. ☒ Drawings - Total Sheets: 19 (Fig(s). 19)
4. Oath or Declaration - Total Pages: 4
  - a. ☒ Newly executed (original or copy)  
☐ New (unexecuted)
  - b. ☐ Copy from a prior application  
(for continuation/divisional with Box 17 completed)
    - i. ☐ DELETION OF INVENTOR(s):  
Signed statement attached deleting inventor(s) named in prior application.
5. ☐ Incorporation By Reference (useable if Box 4b is marked)

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09/16/01  
11/21/00

The entire disclosure of the prior application, from which a copy of the oath or declaration is supplied under Box 4b, is considered as being part of the disclosure of the accompanying application and is hereby incorporated by reference therein.

6. ☐ Microfiche Computer Program (Appendix)
7. ☐ Nucleotide and/or Amino Acid Sequence Submission (if applicable, all necessary)
- a. ☐ Computer Readable Copy
- b. ☐ Paper Copy (identical to computer copy)
- c. ☐ Statement verifying identity of above copies
8. ☐ Assignment and Assignment Recordation Form
9. ☐ 37 C.F.R. 3.73(b) Statement ☐ Power of Attorney
10. ☐ English Translation Document (if applicable)
11. ☐ Information Disclosure Statement with PTO-1449 and References
- ☐ Copies of Information Disclosure Statement Citations
12. ☐ Preliminary Amendment
13. ☒ Return Receipt Postcard
14. ☐ Small Entity Statement(s) ☐ Independent Inventor
- ☐ Small Business Concern
- ☐ Non-Profit Organization
- ☐ Statement Filed in Prior Application; Status Still Proper and Desired
15. ☒ Foreign Priority is Claimed as Follows:
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- \_\_\_\_\_
- ☐ If Foreign Priority is Claimed, Certified Copy of the Above Priority Document(s) is Submitted Herewith
16. ☐ Other: \_\_\_\_\_
17. ☐ Continuation ☐ Divisional ☐ Continuation-in-Part of
- Prior Application No.: \_\_\_\_\_ filed \_\_\_\_\_
- ☐ Complete Application Based on Provisional Application No.: \_\_\_\_\_
- filed \_\_\_\_\_

18. ☒ A new power of attorney or authorization of agent (PTO/SB/81) is as follows:
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- ☒ Please remove as power of attorney: Please remove as power of attorney: Rodger L. Tate, Reg. No. 27,399 and James Remenick, Reg. No. 36,902.
- ☒ Please add as power of attorney: Please add as power of attorney: Richard G. Berkley, Reg. No. 25,465.
19. Please address all correspondence to: Attention: Robert L. Troike  
Baker Botts L.L.P.  
The Warner, Suite 1300  
1299 Pennsylvania Avenue, N.W.  
Washington, D.C. 20004-2400

Commissioner for Patents

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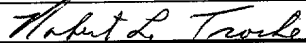
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Respectfully submitted,

By: Robert L. Troike  
Robert L. Troike  
Registration No. 24,183

Enclosures  
RLT/dh

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Typed or Printed Name	Robert L. Troike			Registration No.	24,183																																								
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# **SUPER-REGENERATIVE MICROWAVE DETECTOR**

## **FIELD OF INVENTION**

This invention relates to microwave detectors and more particularly to a very sensitive detector of millimeter wavelength (millimeter-wave) RF signals and sub-millimeter wavelength (sub-millimeter-wave) RF signals.

## **BACKGROUND OF INVENTION**

Microwave detectors are essential microwave components. They convert RF energy into electrical form for analysis. The subject detector can be used anywhere high sensitivity is required in a simple detector. Obvious applications include simple sub-millimeter-wave imagers, phased array receivers, proximity detecting warhead fuses, and communication links. Since the detector is an oscillator, it can be configured as a transmitter and a receiver in the same circuit. This permits its use in simple wideband communication links and proximity detectors.

Homodyne detectors detect RF energy at the carrier frequency, and output the information carried on the RF signal as a demodulation waveform. To minimize power consumption in wideband front-end amplifiers, these detectors should be very sensitive.

Typically, Schottky diodes are used as square-law detectors at millimeter (mm) wavelength (>50 gigahertz or >50 GHz) frequencies. Often, the millimeter-wave signal is down-converted to a lower frequency for easier amplification and detection at a so-called intermediate frequency. Schottky detectors can operate directly at deep millimeter-wavelengths (> 500 GHz), but they are very lossy and have noise figures on the order of 12 dB at 500 GHz. To override the negative effect of this high loss, a low-noise >100GHz preamplifier must be placed ahead of the detector. However, this amplifier component not easily provided by transistor technology due to the extreme frequencies involved. So, previous detectors have either high loss or require complicated RF circuitry to efficiently detect millimeter-wave signals.

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## SUMMARY OF INVENTION:

In accordance with one embodiment of the present invention this invention solves the problem of providing very sensitive direct detection of millimeter-wave and sub-millimeter-wave RF signals. This invention creates an oscillator using resonant tunneling diodes (RTDs) at the center frequency of the signals of interest. The oscillator is periodically shut down (quenched) and restarted such that the duty cycle of the oscillator varies with the strength of the input signal coupled to the oscillator. The oscillator startup time is directly and linearly related to the strength of the input signal. The oscillating detector, called a super-regenerative detector, is also highly sensitive, and can directly detect RF signals at or below the thermal noise floor of the system. The rate at which the oscillator is quenched directly controls the bandwidth and sensitivity of the circuit. The circuit is capable of operating to the oscillation limit ( $f_{max}$ ) of RTDs, or about 2000 GHz.

## DESCRIPTION OF DRAWING:

In the drawing:

Figure 1 shows a schematic of a conceptual super-regenerative millimeter-wave detector;  
Figure 2 shows the current versus voltage response of a typical resonant tunneling;  
Figure 3 shows the differential conductance of the resonant tunneling diode of Figure 2;  
Figure 4 shows a schematic of a conceptual quench generator as used to excite a super-regenerative millimeter-wave detector;  
Figure 5 shows a schematic of a conceptual power meter as used in a millimeter-wavelength detector;  
Figure 6 shows a schematic of a super-regenerative millimeter-wave detector with component values;  
Figure 7 illustrates a SPICE simulation of the response of the millimeter wavelength circuit represented in Figure 6;  
Figure 8 illustrates an expanded view of Figure 7 during a time where the detector is sensing an external signal;  
Figure 9 illustrates a SPICE simulation of the response of the millimeter wavelength circuit represented in Figure 6 for differing levels of input signal strength;  
Figure 10 is an expanded view of Figure 9 during a time where the detector is sensing an external signal;  
Figure 11 illustrates a SPICE simulation of the response of the millimeter wavelength circuit represented in Figure 6 when adjusted to provide a linear response to changes in input signal strength;  
Figure 12 illustrates a SPICE simulation of the circuit of Figure 6 showing the output of a millimeter wavelength power meter used to monitor super-regenerative oscillations;  
Figure 13 illustrates a super-regenerative detector of free-space millimeter-wavelength signals;  
Figure 14 shows the top view of a monolithic quenched oscillator for the detection of free-space millimeter wavelength signals;  
Figure 15 shows a schematic of the quenched oscillator of Figure 14;  
Figure 16 shows the top view of a free-space power meter to be used to monitor the radiated power from a quenched millimeter wavelength oscillator;  
Figure 17 shows a schematic of the millimeter wavelength power meter of Figure 16;  
Figure 18 shows the schematic of a conceptual millimeter wavelength super-regenerative detector using a push-pull arrangement of resonant tunneling diodes.  
Figure 19 is a schematic of a conceptual super-regeneration detector using a single resonant tunneling diode integrated with a tapered slot transmission line antenna.



## DESCRIPTION OF PREFERRED EMBODIMENTS

When power is applied to any electronic oscillator, steady state oscillations build up from random noise fluctuations within the circuit. The turn-on delay, the time between power-up and stable oscillation, is controlled by the overall gain, feedback, and noise level within the circuit. This characteristic turn-on time can be shortened by injecting a coherent, resonant signal into the oscillator. The circuit gain amplifies the injected signal, feeding back the amplified wave until stable oscillation is achieved. The final amplitude of the oscillations may be a million times greater than the strength of the injected input signal. This effect, called super-regeneration, can be used to build simple, highly sensitive radio frequency detectors using resonant tunneling devices. Due to their high intrinsic speed, super-regenerative detectors based on resonant tunneling devices can operate well above 1000 GHz. Figure 1 shows a schematic of a conceptual super-regenerative millimeter-wave (30-300 GHz) detector 10. A resonant tunneling diode (RTD) 11 is coupled to a tuned circuit composed of capacitor 12 and inductor 13 forming an oscillator with characteristic frequency  $F$ . The oscillator is coupled to a signal source represented by current source 14 and source resistance 15, and the circuit is energized by a quench waveform generator 16. The output of the detector is taken from power meter 17 which measures the average oscillator power.

The waveform generator 16 applies periodic power to the RTD such that the circuit undergoes repeated build-up and decay of self-oscillations even in the absence of external signal 14. We refer to the on-off modulator as the "quench generator" and the on-off rate as the "quench" frequency. When an external signal of frequency  $F$  is applied to the circuit the buildup of oscillation occurs earlier in the quench cycle so that the duty factor of oscillation changes in proportion to the strength of the input. A measurement of the average energy of circuit oscillations provides a direct measure of the relative strength of the input signal. Since the average oscillation power is related to the signal strength, the changes in the measured power over time correspond to changes in the amplitude of the signal "carrier." Information impressed on the signal carrier by amplitude modulation can thus be recovered or detected by circuit 10. According to well-known information theory, the instantaneous bandwidth of information that can be unambiguously detected by the circuit is about one half of the quench frequency. The periodic waveform generator 16 is also an oscillator operating at a relatively low frequency, preferably less than 10% of the RF carrier frequency. For example, a circuit designed to detect 300 GHz signals might have a quench circuit oscillate at 10 GHz if it desired to detect modulated signals with a bandwidth of up to 5 GHz.

As is very well known in the art, a resonant tunneling diode, also known as the quantum well diode, utilizes the tunneling of electrons through a pair of potential energy barriers to produce negative differential conductance effects. A RTD typically consists of a multi-layer stack (heterostructure) of epitaxially grown semiconductor material so formed to produce a single quantum energy well surrounded by twin energy barriers. Electrons incident upon this structure will be reflected from the structure except for certain well defined energies. These energies correspond to resonant energy levels within the quantum well, and conductance through

the structure for these energies is very efficient. A typical design for an RTD is given in Table 1. These layers are grown using molecular beam epitaxy or chemical vapor deposition methods using compounds of Indium (In), Arsenic (As), Gallium (Ga), Aluminum (Al), and Phosphorous (P). RTDs based on InGaAs quantum wells and AlAs tunnel barriers are easily grown on standard InP substrates. Various dopants such as silicon and boron can be used to alter the conductivity of each layer. Such diodes can also be fabricated using AlGaAs compounds on GaAs substrates.

Table 1. Typical Resonant Tunneling Diode Heterostructure.

Layer Name	Material	Doping Density	Thickness in Angstroms or Monolayers
Top Contact	InGaAs	2E19/cc	500 Angstroms
Spacer	InGaAs	undoped	50 Angstroms
Aluminum	AlAs	undoped	6.5 monolayers
Quantum Well	InGaAs	undoped	10 Angstroms
Quantum Well	InAs	undoped	20 Angstroms
Quantum Well	InGaAs	undoped	10 Angstroms
Aluminum	AlAs	undoped	6.5 monolayers
Spacer	InGaAs	undoped	50 Angstroms
Top Contact	InGaAs	2E19/cc	2000 Angstroms
Substrate	InP	undoped	0.018 inches

Under electrical bias between the top contact and the bottom contact, the electrical current in the diode will first rise with increasing bias, then precipitously drop with further bias, then rise again with even further bias as shown in Figure 2. Figure 2 shows the current versus voltage response of an RTD of Table 1 that exhibits 50,000 amperes/cm<sup>2</sup> of current at the first resonance. The response is for a device of 1 square micrometer of cross-sectional area. The initial rise and peak in the diode current, at about 0.14 volts of bias, is due to quantum mechanical tunneling of electrons through the lowest energy conduction band resonance established within the heterostructure. The second rise in current after 0.3 volts of bias is due to the onset of tunneling through the next higher energy resonance. The falloff in current, at bias voltages between 0.14 and 0.3 volts in the figure, has a negative slope. The negative differential conductance (or conversely the negative differential resistance) associated with this bias regime for this device is shown in Figure 3. Within this bias range the RTD can be used as a gain element for amplification or oscillation. The maximum negative differential conductance occurs at about 0.17 volts in this exemplary device, which is also the bias point of maximum available gain. Connecting the RTD to a resonant electrical circuit can produce amplification and self-starting oscillation if the magnitude of this gain exceeds the losses within the circuit. This ability to support amplification and oscillation within an electronic circuit is characteristic of any electrical device that exhibits negative differential conductance. REF: "Basic Theory And Application of Tunnel Diodes," S.P. Gentile, Van Nostrand, Princeton N.J. (1962) At the present state of the art, the resonant tunneling diode is the fastest semiconductor with intrinsic electronic gain. RTDs have been shown to oscillate above 700 GHz. (REF:Brown et. al. "High Frequency

Resonant Tunneling Oscillators," Microwave and Optical Technology Letters, Vol. 4, No.1, Jan 1991, pp-19-23) Therefore, the fastest oscillators based on semiconductor gain elements must currently employ resonant tunneling diodes. A millimeter-wave and sub-millimeter wavelength detectors based on the super-regeneration principle should employ resonant tunneling diodes.

Based on the need for circuit in detector 10 to controllably oscillate using a RTD, the electrical properties of quench generator 16 in detector 10 must meet several requirements. First, it must present a very low impedance at the signal frequency so that the size of, or changes in, the generator do not affect the resonant frequency of the detector. Since the generator preferably operates at a frequency much lower than F and must supply operating power to the detector, it may typically be composed of relatively large, low frequency components. The size of these components and their interconnection wiring may be of the order of a wavelength at F, which could cause undesired parasitic resonance and oscillations in the detector 10. In practice, the requirement of a low impedance can be met by placing a capacitor across the output terminals of the generator 16. This signal bypass capacitor 18 is shown in Figure 4. The second requirement of the generator is that it present a sufficiently low dc resistance to the detector circuit. In order for the circuit 10 to oscillate controllably and in a sinusoidal fashion, the dc resistance presented by the circuit to RTD 11 must be less than the magnitude of the peak negative differential resistance of the RTD. In equation form, proper operation of detector 10 as a quenched superregenerative detector requires that

$$-R_{RTD}(dc) > R_{Circuit}(dc) \quad \text{Equation 1}$$

where  $R_{RTD}(dc)$  is the differential dc resistance of the RTD and  $R_{Circuit}(dc)$  is the equivalent differential dc conductance of the circuit connected to the RTD. As an example, the peak negative differential resistance of the diode of Figure 3 is  $(-1/8.4E-3) = -119$  ohms. For this RTD to be correctly used in detector 10, the total effective dc resistance across the RTD must be less than 119 ohms. To provide design margin,  $R_{Circuit}$  is preferably limited to a value no greater than  $\frac{1}{2}$  of  $(-R_{RTD})$ .

Since the quench generator 16 is placed in series with the RTD in detector 10, it follows that the dc resistance of the quench generator must be less than the magnitude of the peak negative differential resistance of the RTD, and less than  $\frac{1}{2}$  of this value for design margin. If the rest of the circuit also has non-zero dc resistance, the dc resistance of the generator must be reduced further by a similar amount.

The required low dc resistance of generator 16 can be ensured by using a shunt bias resistor 19 placed across the output terminals of the generator. The value of resistor 19 is adjusted down in value until the parallel combination of resistor 19 and the output resistance 20 of voltage source 21 meets the oscillation condition set by Equation 1. For some embodiments of the generator voltage source 21, its output resistance 20 may be sufficiently low to avoid the need for resistor 19.

The combination of voltage source 21 and series resistor 20 represents an idealized waveform generator, but closely approximates standard laboratory signal generators. Typically, the output resistance of radio frequency generators is 50 ohms. However, RF transformers may

be used to step-up or step-down the impedance and resistance of the generator output to whatever value is required by detector 10. Generators with sine-like, rectangular-like, triangle-like, and sawtooth-like waveforms can be used as the quench generator.

The power meter 17 in detector 10 must provide an output signal that is proportional to the average RF power contained in the detector circuit at the signal frequency  $F$ . This can be accomplished as shown in Figure 5 using a Schottky diode envelope detector. A Schottky diode 22, with sufficient switching speed to rectify signals at frequency  $F$  is connected to inductor 13 and an RC filter network comprised of capacitor 24 and resistor 25. A low noise amplifier 27 is connected to the RC network to buffer the power meter circuit from subsequent instrumentation. Power meter 17 operates as follows. RF energy at frequency  $F$  is periodically stored and released from inductor 13. Some of the RF voltage across inductor 13 is applied across diode 22 and the parallel combination of capacitor 24 and resistor 25. When forward biased by the RF voltage, diode 22 acts as a resistor of low value and the capacitor becomes partially charged. When reversed biased by the changing polarity of the RF voltage, diode 22 acts as an open circuit so that capacitor 24 does not significantly discharge back through diode 22 during this half cycle. Thus on each RF cycle, the capacitor tends to accumulate a net charge proportional to the strength of the received RF energy. Resistor 25 provides a leakage path for charge stored on the capacitor so that the long-term average voltage across the capacitor rises and falls with the long-term average of the RF voltage across inductor 13.

Preferably diode 22 should be connected to a point on inductor 13 that provides the minimum loading of the oscillator while providing sufficient RF voltage to be detected. Alternatively, diode 22 can be magnetically coupled to inductor 13 by connecting a grounded inductor between diode 22 and ground, and then placing this inductor in the proximity of inductor 13.

Preferably the RC time constant of the parallel combination of capacitor 24 and resistor 25 should be roughly equal to the quench period ( $1/\text{quench rate}$ ) of quench generator 16 but significantly longer than the signal period ( $1/F$ ). For example, if power meter 17 is used to measure 100 GHz oscillation from an oscillator quenched at a 1.67 GHz rate, capacitor 24 might have a value of 20 picofarads and resistor 25 should then have a value of about 50 ohms. The low-noise amplifier 27 is connected across the RC network to serve as a buffer of the measured power. The output of this amplifier represents the overall output of detector 10. If the input resistance of amplifier 27 is very low then resistor 25 should be adjusted so that the overall RC time constant for the power meter 17 is roughly equal to the period of the quench rate for detector 10.

Figure 6 shows a complete circuit for a super-regenerative detector 10 based on a quenched RTD oscillator and a Schottky diode power meter. The quench generator subcircuit consists of a 2 pF capacitor, a 35 ohm bias resistor, and an ideal rectangular waveform generator with a 50 ohm source resistance. The equivalent dc resistance of the quench circuit is about 20 ohms. The generator has a peak open circuit output voltage of 0.9 volts and a minimum open circuit output voltage of 0.46 volts. The quench generator has a fixed repetition rate of 1.67 GHz ( $1 \text{ GHz} = 1\text{E}9 \text{ Hertz}$ ). The RTD has a peak current density of 50,000 amperes/cm<sup>2</sup> and an active area of 3.1 square micrometers. The input signal source consists of an ideal gated RF current

source and a 75 ohm shunt resistor. The signal source has an on-off duty factor of 50% and a pulse repetition rate of 833 MHz (1 MHz = 1E6 Hertz). The detector has a center oscillation frequency of 116 GHz. The signal source is ideally set equal to the center oscillation frequency. The power meter consists of an ideal power meter. The power meter subcircuit consists of a Schottky diode, 20 pF capacitor, a 50 ohm resistor, and a low noise amplifier.

Figure 7 shows a 1.8 nanosecond long simulation of the operation of detector 10 in the embodiment of Figure 6. Trace-A records the voltage across the 2 pF capacitor. Trace-B records the voltage across the 30 pH inductor. Trace-C records the voltage across the RTD. Trace-D records the current provided by the RF signal source. Operation of the detector proceeds as follows. Initially the quench waveform has a high (0.9 Volt) value. This results in a potential difference of 0.4 volts across the 2 pF capacitor and the RTD. With reference to Figure 3, the RTD is thus biased in a region of slightly positive differential resistance. When the generator voltage changes to its minimum value, the dc voltage across the 2 pF capacitor and the RTD drops to about 0.19 volts with a time constant of about  $20 \text{ ohms} \times 2 \text{ pF} = 40 \text{ picoseconds}$ . At a relative point in time near 0.45 nanoseconds, the RTD becomes biased within its region of negative differential conductance and the circuit builds up oscillations at its resonant frequency. The onset of oscillation in the circuit at 0.45 nanoseconds occurs while the input signal is applied to the circuit. Soon after oscillation begins, the quench waveform voltage across the RTD rises toward its maximum value of 0.4V. This rise biases the RTD out of negative differential conductance and into positive differential conductance. At this bias the RTD acts as a passive positive resistance and dissipates the RF energy stored within the circuit. On the next cycle of the quench waveform the circuit breaks into oscillation at a relative time of about 1.1 nanoseconds into the simulation. In this cycle the input signal is turned off, and the oscillator starts naturally due to random electrical fluctuations in the circuit. It will be seen that the duration and strength of the spontaneous (input off) oscillation of the circuit is less than the driven (input on) oscillation condition. The correlation of the strength of the RF oscillation with the presence or absence of the input is clearly evident. Figure 8 provides a time-expanded view of the circuit of Figure 6 when operating in the driven mode.

Figure 9 plots the time domain response of the circuit in Figure 6 to various levels of input signal power. Trace E records the voltage across the 2 pF capacitor. Trace F records the response of the circuit to an average input signal power of 0.002 picowatts. Trace G records the response of the circuit to an average input signal power of 0.2 picowatts. Trace H records the response of the circuit to an average input signal power of 20 picowatts. Trace I records the response of the circuit to an average input signal power of 2000 picowatts. During the time when the input source is on, it is seen that the duration and total RF power of the oscillation is related to the logarithm of the strength of the input signal. The oscillation duration and strength of the oscillation during the undriven timeframe (around 1 nanosecond into the simulation) is independent of input signal strength. Therefore, the measurement of the RF voltage or power in the circuit provides a direct measure of the presence and strength of the input signal. Figure 10 shows an expanded view of Figure 9 for one quench cycle. Trace J in Figure 10 shows the input signal source current.

The precise functional relationship between the input signal power and the average RF power of the oscillating detector is controlled by the shape, rate and amplitude of the quench

waveform. The operation of the circuit in Figure 6 using the simulation conditions of Figure 10 produces a roughly logarithmic increase in average oscillation power with the increase in the power of the input signal. A linear response of detector 10 can be obtained by adjusting the quench waveform so that the RF oscillations are not allowed to reach a steady state condition. Figure 11 shows a simulation of the same circuit as in Figure 6, but where the duty factor of the rectangular quench waveform is reduced to roughly  $180\text{ps}/1200\text{ps} = 15\%$ . For this quench waveform, the time during which the RTD is biased at maximum negative differential conductance is so shortened that the oscillation waveform never reaches a steady state value. In this mode of operation, the oscillation power increases roughly linearly with the strength of the input signal. Trace K records the voltage across the 2 pF capacitor in Figure 6. Trace L records the response of the circuit to an average input signal power of 10 picowatts. Trace M records the response of the circuit to an average input signal power of 40 picowatts. Trace N records the response of the circuit to an average input signal power of 160 picowatts. A linear response of the detector may be required when it is used to detect amplitude modulated analog signals while a logarithmic response may be useful when detecting pulsed RF signals modulated by on-off digital information.

The output of the power meter in the circuit of Figure 6 is shown in Figure 12 for the case of a gated 116 GHz input signal. The signal source is alternately turned on and off every 2.5 nanoseconds. The quench rate is 1.67 GHz. Trace-P shows the voltage across the 20 pF capacitor over time. Trace-Q shows the voltage across the inductor 13 and Trace-R shows the input signal current. The voltage across the 20 pF capacitor has the same general envelop as the modulated input signal. This shows that the detector faithfully recovers the modulation impressed on the input RF signal.

The sensitivity and bandwidth of detector 10 can be controlled by adjusting the quench frequency. A low quench frequency allows very weak signals enough time to stimulate a slow buildup of steady state oscillations in the detector, but necessarily reduces the allowable signal modulation rate. A high quench rate increases the instantaneous detection bandwidth but requires stronger inputs so that oscillation buildup can occur in a shorter time. For weak-signal detection, a very low quench rate can be used to permit detector to recover signals that have an RF power below that of ambient thermal and electrical noise. The quench frequency might be set to several hundred GHz when used to detect large-signal, wide bandwidth sub-millimeter waves. Thus, detector 10 provides a simple means to trade detector bandwidth for sensitivity. This flexibility could be very useful in dynamic noise environments where wideband information can be transferred while the level of ambient and thermal noise is high, while a narrow-band mode can be used to detect signals near the noise floor.

The detector 10 can be embodied in many different ways. A preferred physical embodiment 90 for detector 10 when used to directly detect free space RF signals is shown in Figure 13. The detector consists of a quenched oscillator 100 and an adjacent RF power meter 200. The system is used to detect signals from signal source 300 that propagate in free space. In quenched oscillator 100, the input signal source is replaced by a dipole antenna 102 that is resonant at the desired RF signal frequency  $F$ . This embodiment is shown in Figure 14. A RTD 108 is placed across the dipole terminals. At resonance, the dipole antenna presents to RTD 108 the equivalent electrical effect as a pure resistance in parallel with an RF current source.

Received RF current passes through the RTD to alter its oscillation duty factor. The detector output is taken from power meter 200 which measures the average RF oscillation power radiated from quenched oscillator 100. The quench waveform is applied to RTD 108 via a section of RF transmission line 104. A thin film capacitor 105 and resistor 106 are connected in parallel and placed across the transmission line 104. Capacitor 105 is adjusted to have a low (few ohms) of reactive impedance at the signal frequency  $F$ . Resistor 106 provides the low dc resistance required to meet the oscillation condition set by Equation 1. The electrical length of transmission line 104 between RTD 108 and capacitor 106 is adjusted to be one quarter wavelength at the signal frequency. It is well known that a line of this length (or any odd integer multiple thereof) will present an impedance to the RTD equal to  $(Z_{\text{line}})^2/Z_{\text{quench}}$ , where  $Z_{\text{line}}$  is the characteristic impedance of the transmission line at the signal frequency and  $Z_{\text{quench}}$  is the impedance of the quench generator 16 at the signal frequency.  $Z_{\text{quench}}$  is equal to the impedance of the parallel combination of capacitor 105, resistor 106, and the quench generator. If the quench impedance is very much less than the line impedance then the impedance of the quench generator as seen by the RTD becomes very high. As a result of the use of line 104 the quench generator does not place a significant load resistance on the RTD at the signal frequency. At relatively low frequencies however, the value of  $Z_{\text{line}}$  is effectively the dc resistance of the wires that makeup the line and this resistance can be made arbitrarily small. As a result of the use of resistor 106 the dc resistance presented to the RTD by the line-generator circuit can be kept small enough to satisfy the requirement for oscillation while allowing effective quenching of the oscillator over a broad range of frequencies.

If fabricated on an Indium Phosphide substrate, a detector 100 with a center frequency of 100 GHz will have the following dimensions. Dipole antenna 102 will be about 200 micrometers in length and 20 micrometers wide. The line 104 will be about 100 micrometers in length, use 10 micrometer wide lines, and have a center-to-center line spacing of about 20 micrometers. More generally, the length of line 104 can be selected so that it has an electrical length equal to any odd integral number of quarter wavelengths at the signal frequency  $F$ . Since the RTD 108 will have an inherent junction capacitance, the detector 100 will be resonant at a signal frequency somewhat less than predicted from the physical length of dipole 102. An electrical equivalent circuit of quenched oscillator 100 is shown in Figure 15. The subcircuit consisting of capacitors  $C_{\text{line}}$  and inductors  $L_{\text{line}}$  represents transmission line 104. Preferably, the RC time constant of bypass capacitor 105 with bias resistor 106 and the quench generator source resistance should be less than the quench frequency. For example, a version of detector 100 with a center signal detection frequency of 100 GHz could use a bypass capacitance of 1 picofarad to effectively serve as a low (0.8 ohms) impedance shunt at 100 GHz. Using a 10 GHz quench rate from a 50 ohm generator, the value of bias resistor 106 can have any value whatever and still result in a RC time constant for the quench circuit of less than 100 picoseconds. For this example, resistor 106 need only be adjusted so that Equation 1 is satisfied by the overall circuit.

Power meter 200 is placed in proximity to dipole 102 so that the oscillation power of the circuit can be measured. Since the quenched oscillator 100 consists of an oscillating RTD connected to an antenna, power meter 200 can be provided by a RF-coupled rectifying antenna placed in the proximity to dipole 102. Figure 16 shows an example of power meter 200 consisting of a dipole antenna 202, a Schottky diode rectifier 208, thin film capacitor 205 and thin film resistor 106. RF energy radiated from quenched oscillator 100 is collected by dipole









17. The detector of Claim 12 wherein said oscillator includes an inductor coupled to said resonant tunneling diodes and a power meter coupled to the inductor for providing the output from the detector.
18. The detector of Claim 12 wherein output from said detector is measured by a free space power meter tuned to the detection frequency
19. A method of detecting the strength of an input signal comprising the steps of: providing an oscillator using at least one resonant tunneling diode resonant at a center frequency of said input signal, and periodically shutting down and restarting the oscillator such that the duty cycle of the oscillator varies with the signal strength of the input signal.
20. The method of Claim 19 wherein said step of periodically shutting down and restarting said oscillator includes the step of providing energy from a signal source to said oscillator for the purpose of controlling the average oscillation time.
21. The method of Claim 20 wherein said step of periodically shutting down and restarting said oscillator includes a quench generator.
22. The method of Claim 21 wherein said quench generator operates at a lower frequency than said oscillator.
23. The method of Claim 22 wherein said quench generator operates at a frequency less than 10 percent of the oscillator frequency.
24. The method of Claim 20 wherein said signal source arrives from an antenna.

### ABSTRACT

A resonant tunneling diode or diode array oscillator (10) including a resonant diode (11) is coupled to a millimeter-wave source (14) and a quench generator (16) for periodically quenching the oscillations so that the average oscillation time of the oscillator is proportional to signal strength of the source (14). The signal source can be from an antenna such as a dipole or tapered slot line antenna.

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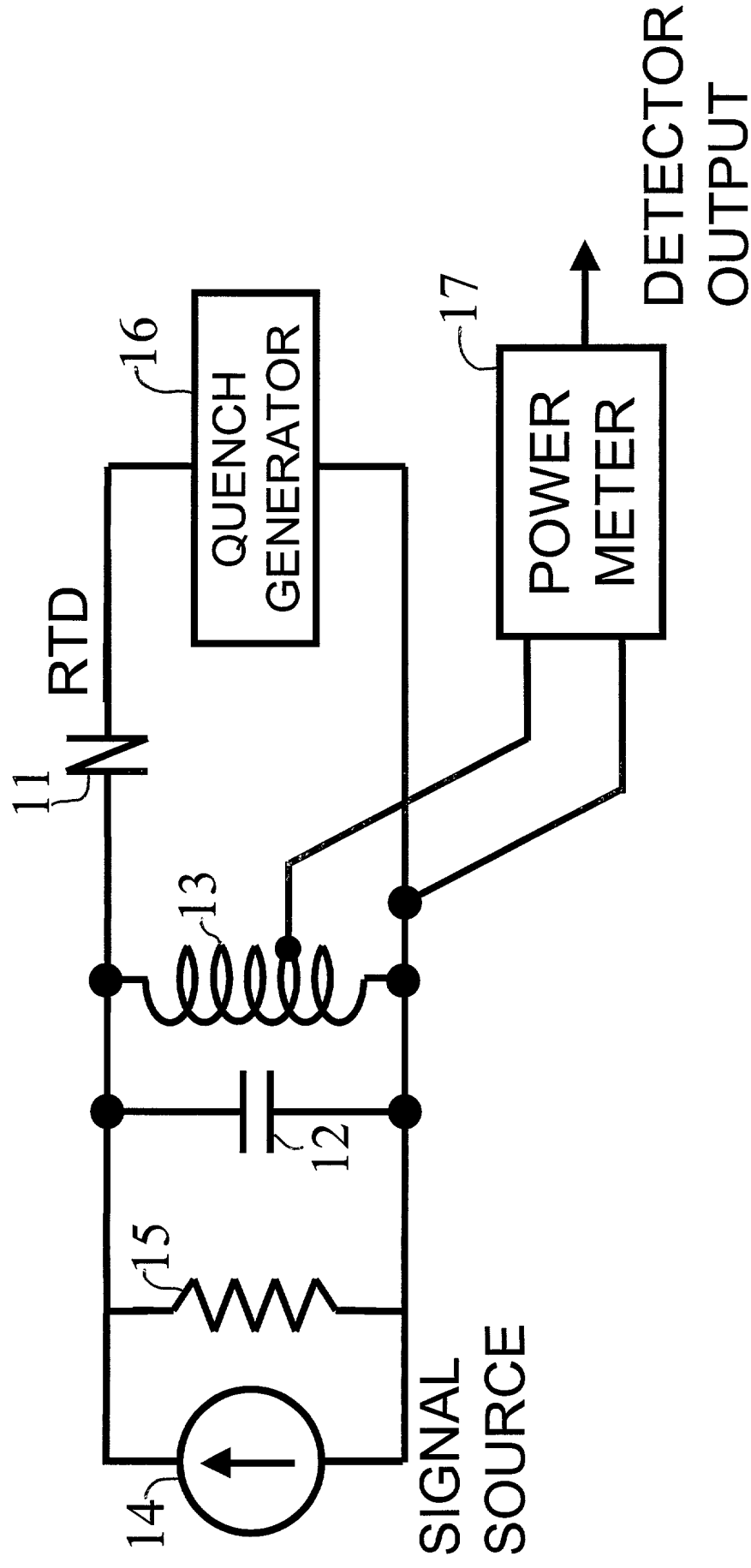


Figure 1

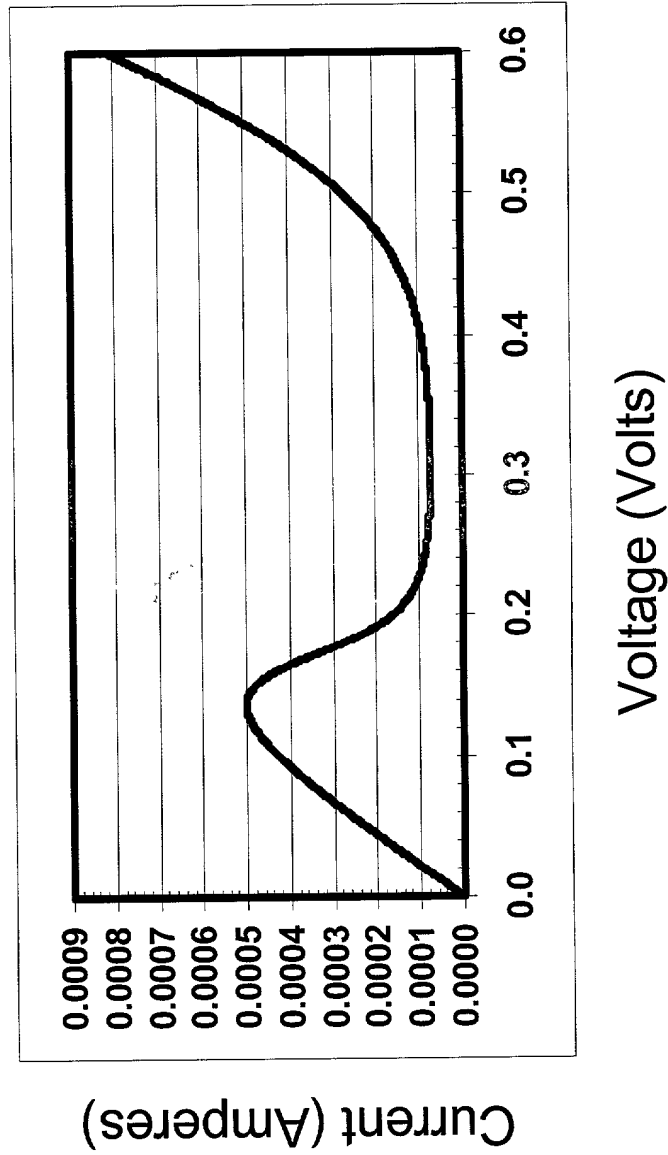


Figure 2

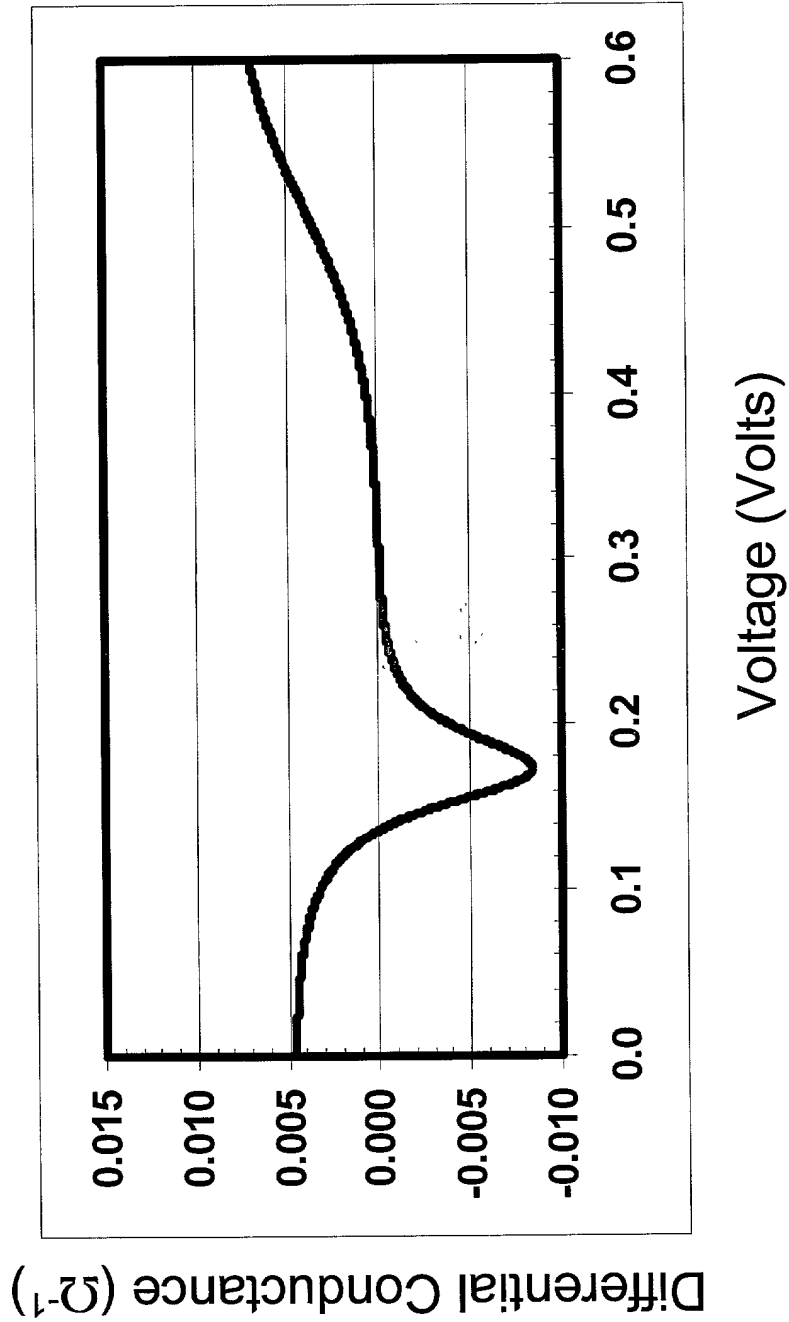


Figure 3

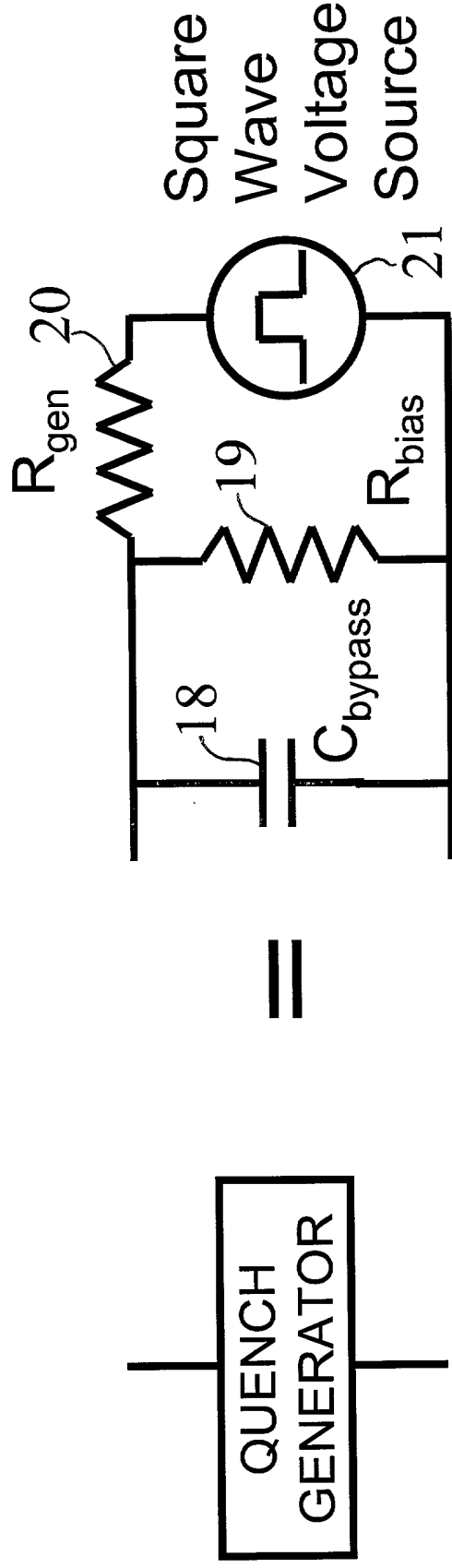


Figure 4



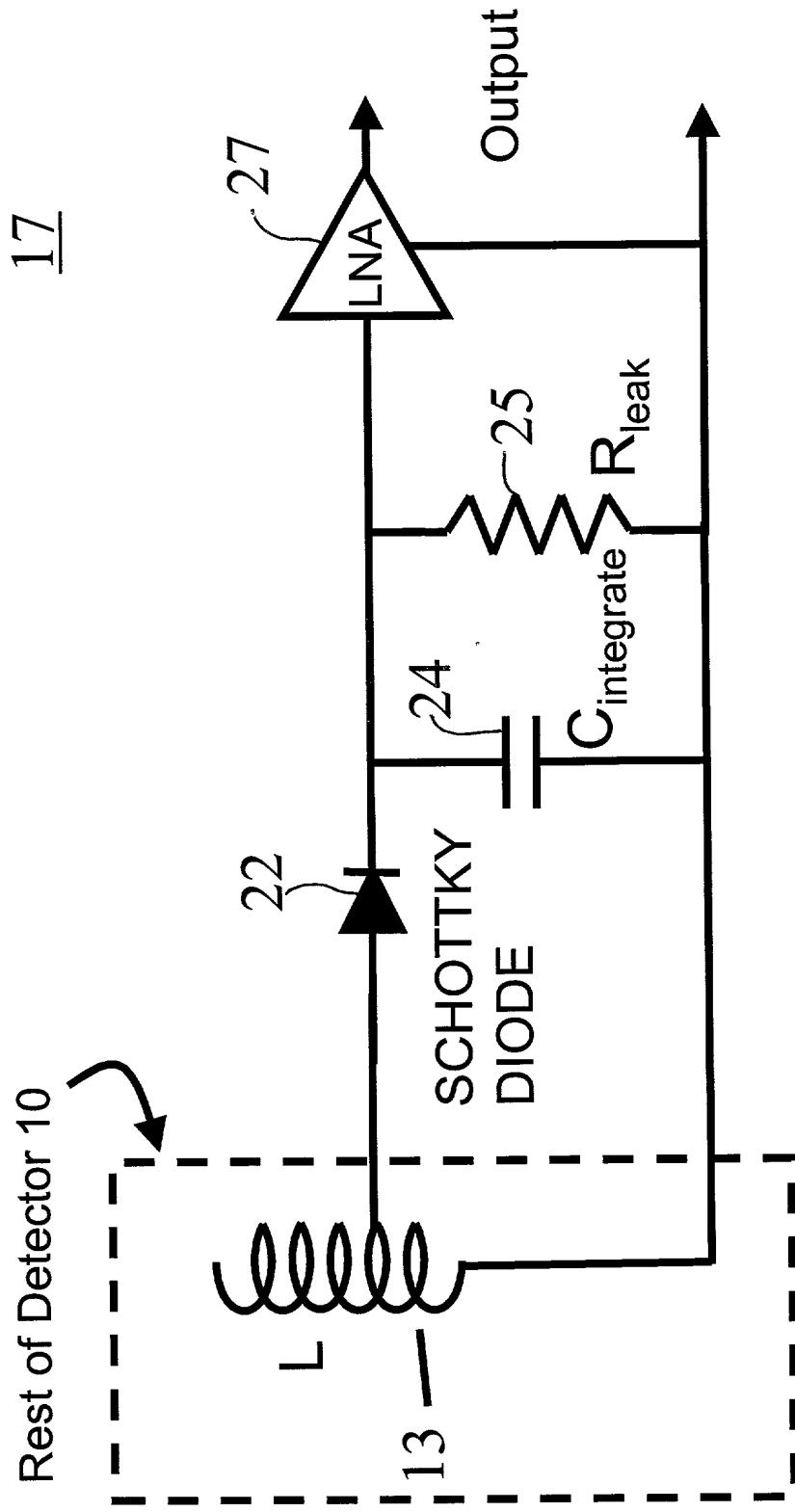
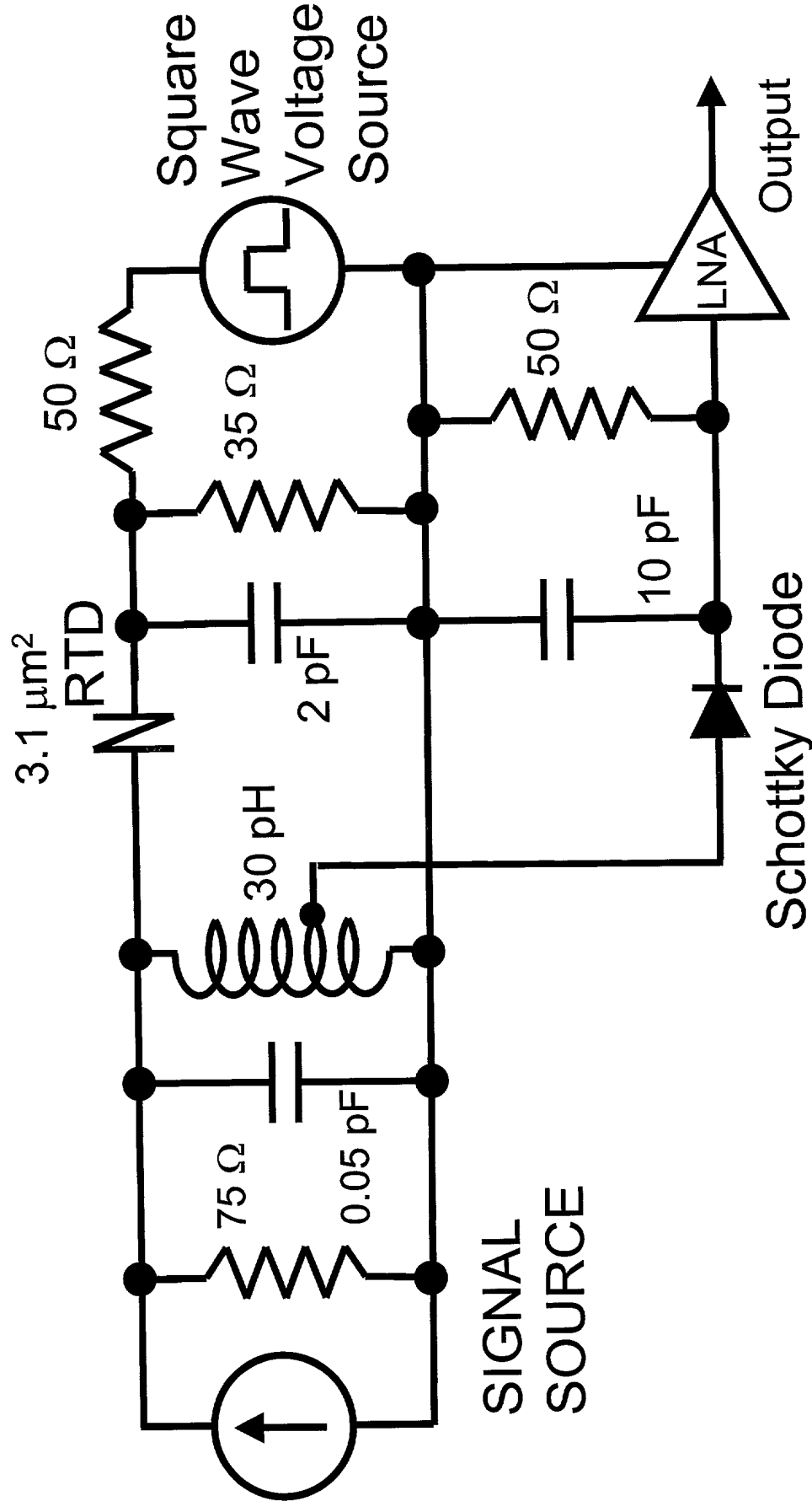


Figure 5



OUTPUT

Figure 6

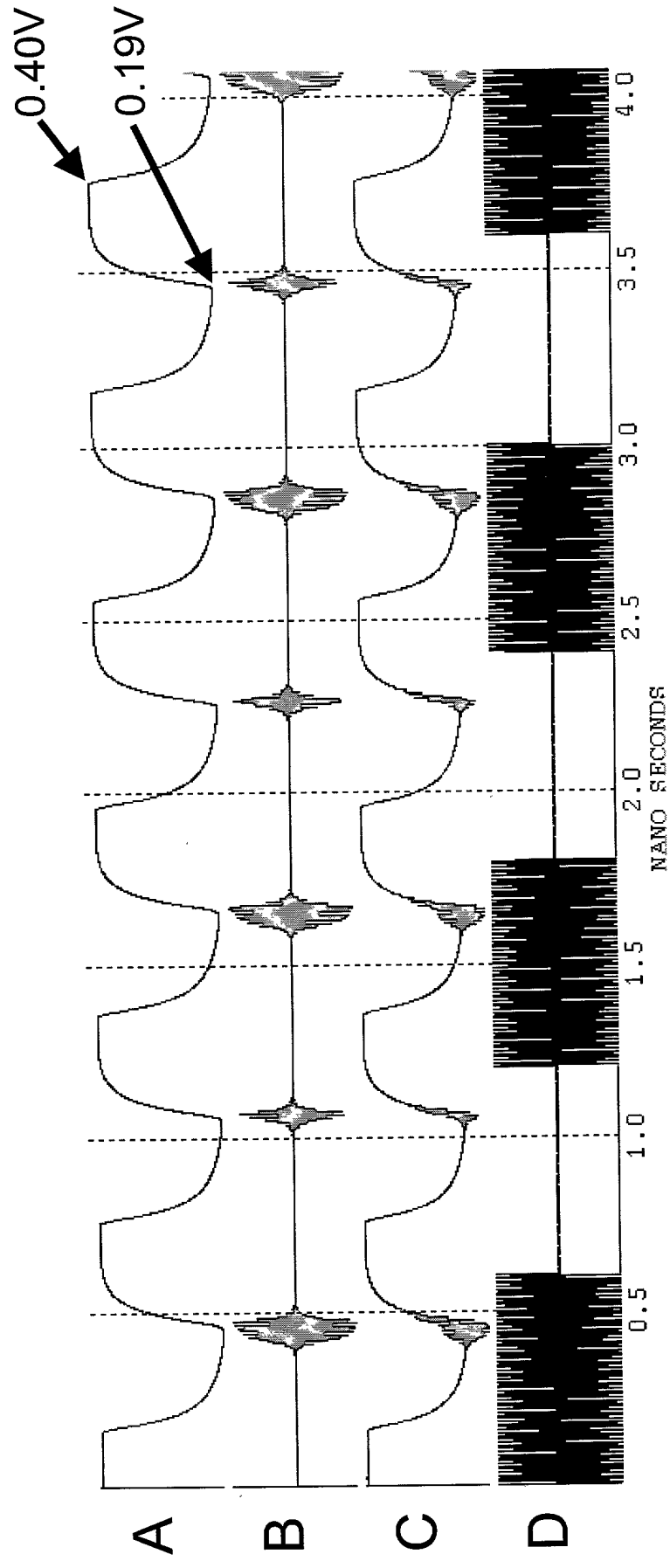


Figure 7

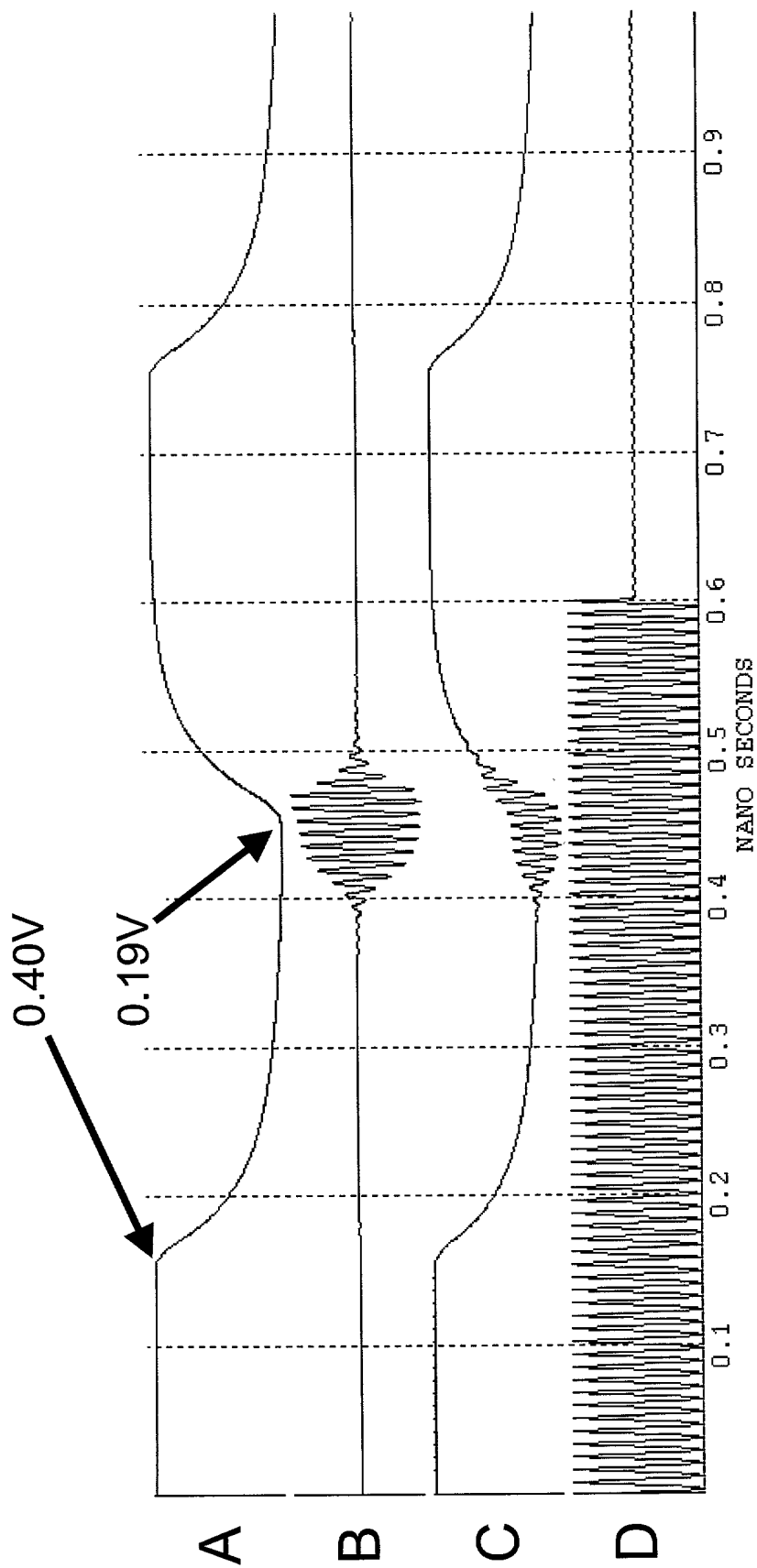


Figure 8

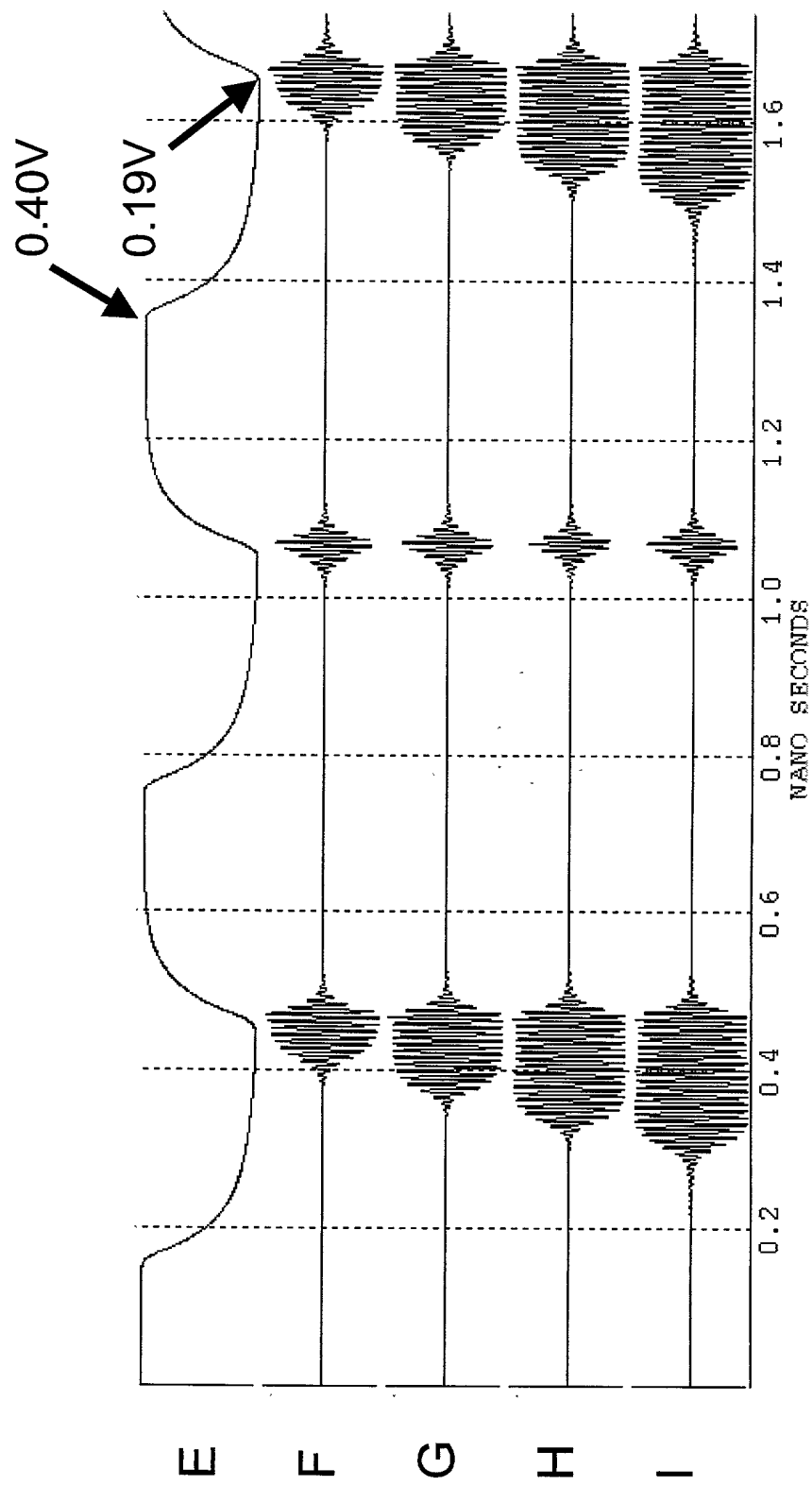


Figure 9

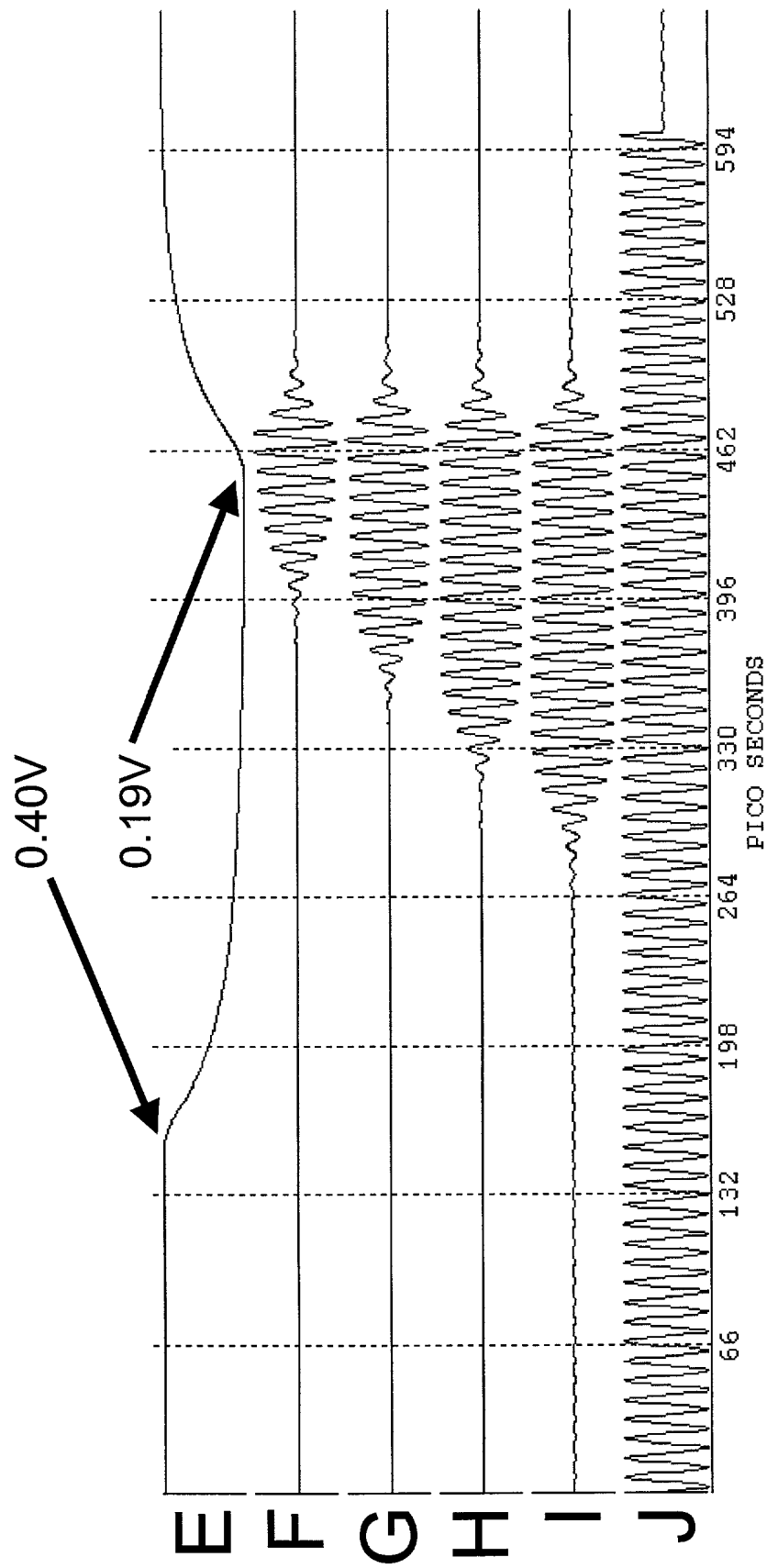


Figure 10

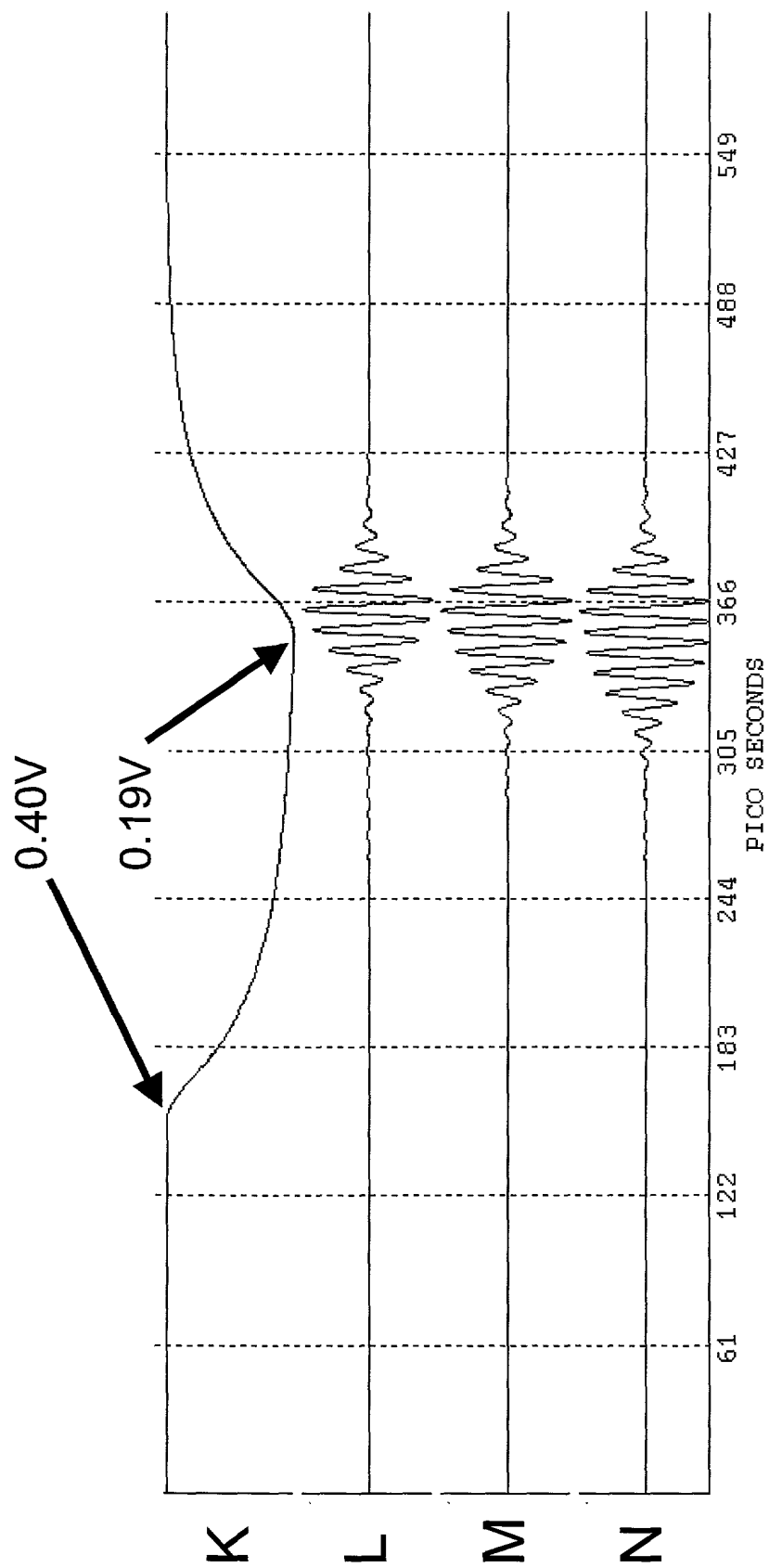


Figure 11

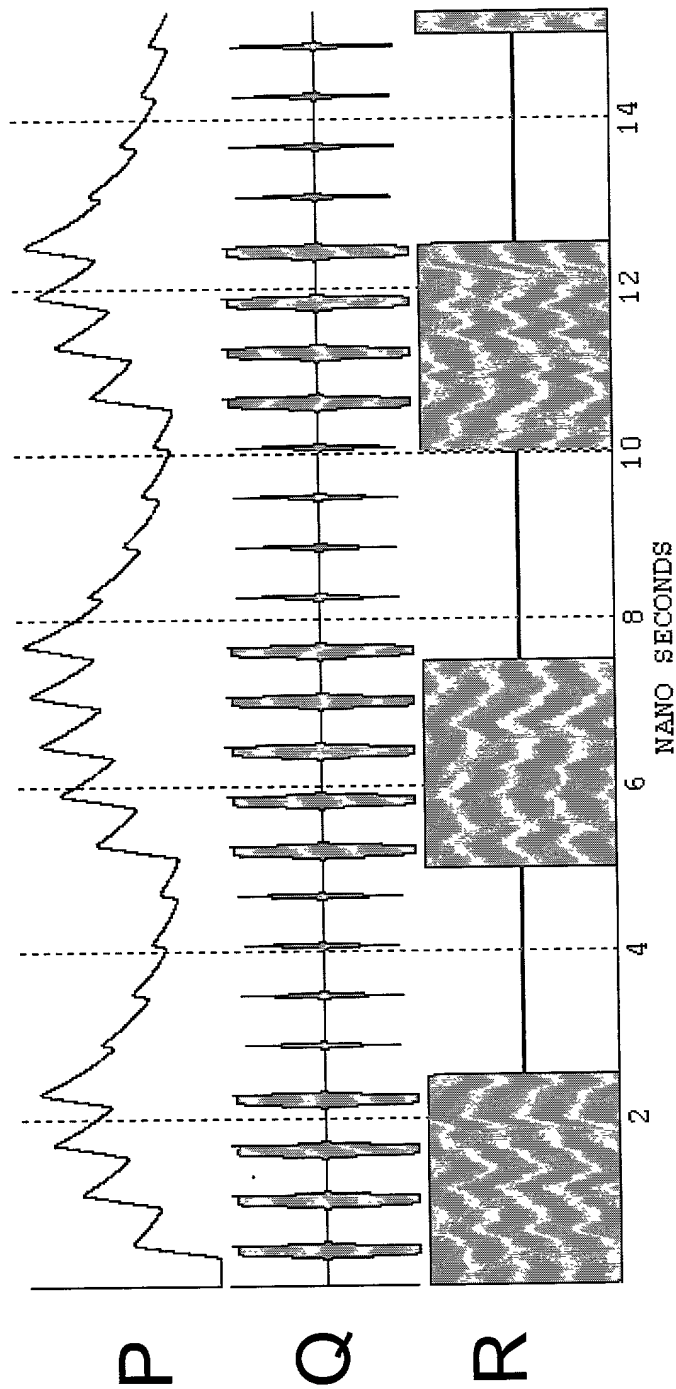


Figure 12



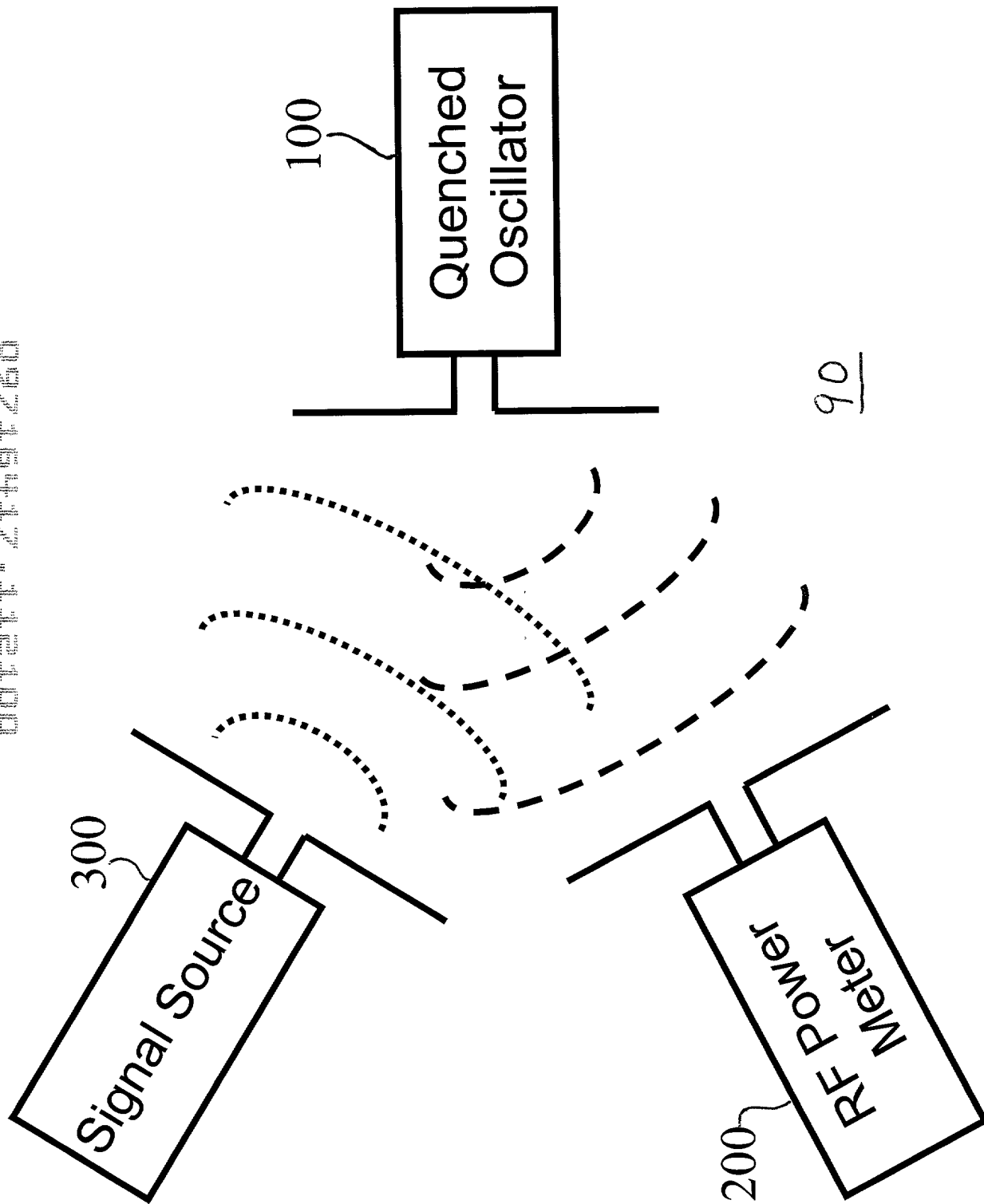


Figure 13

# Top View of Quenched Oscillator

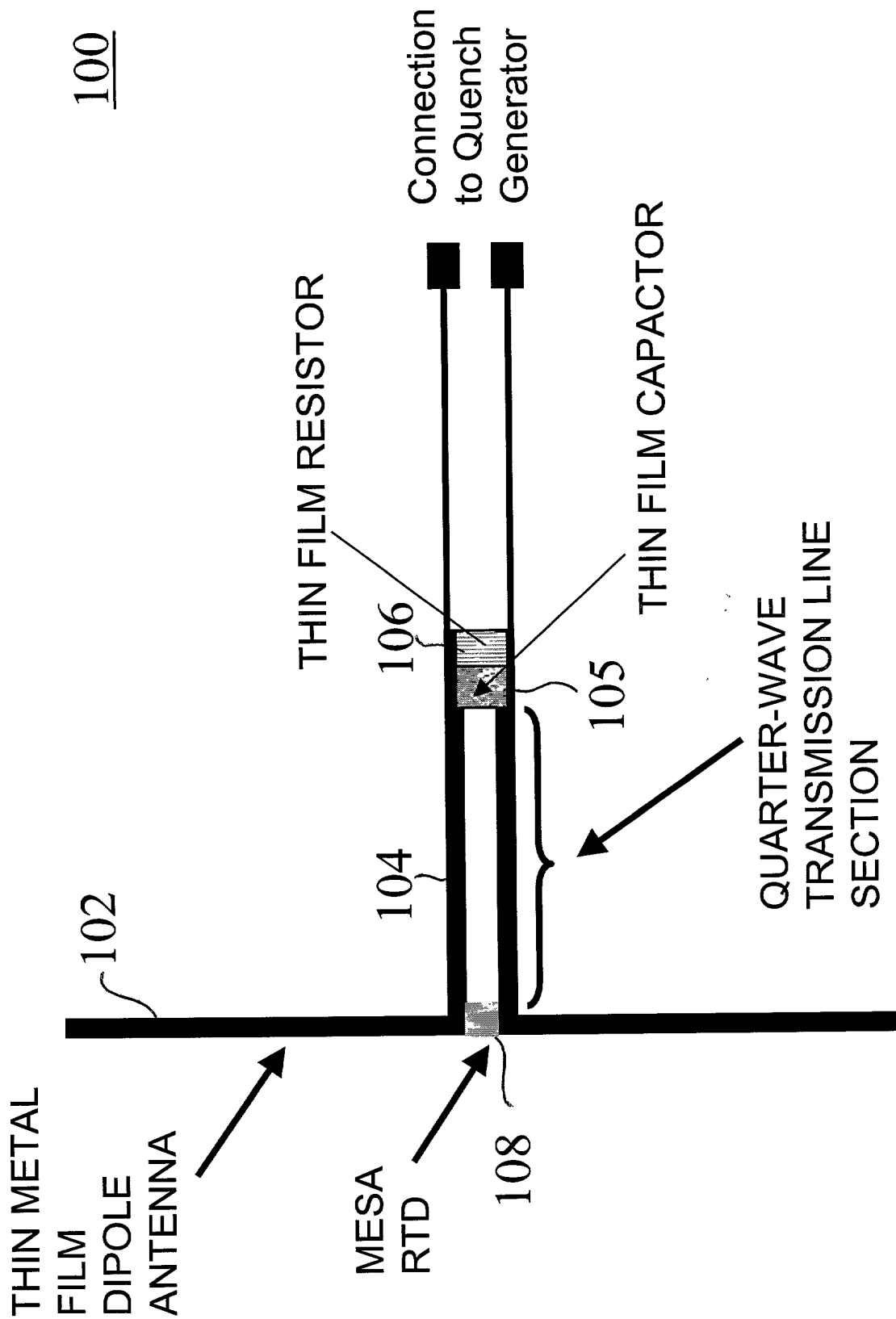


Figure 14

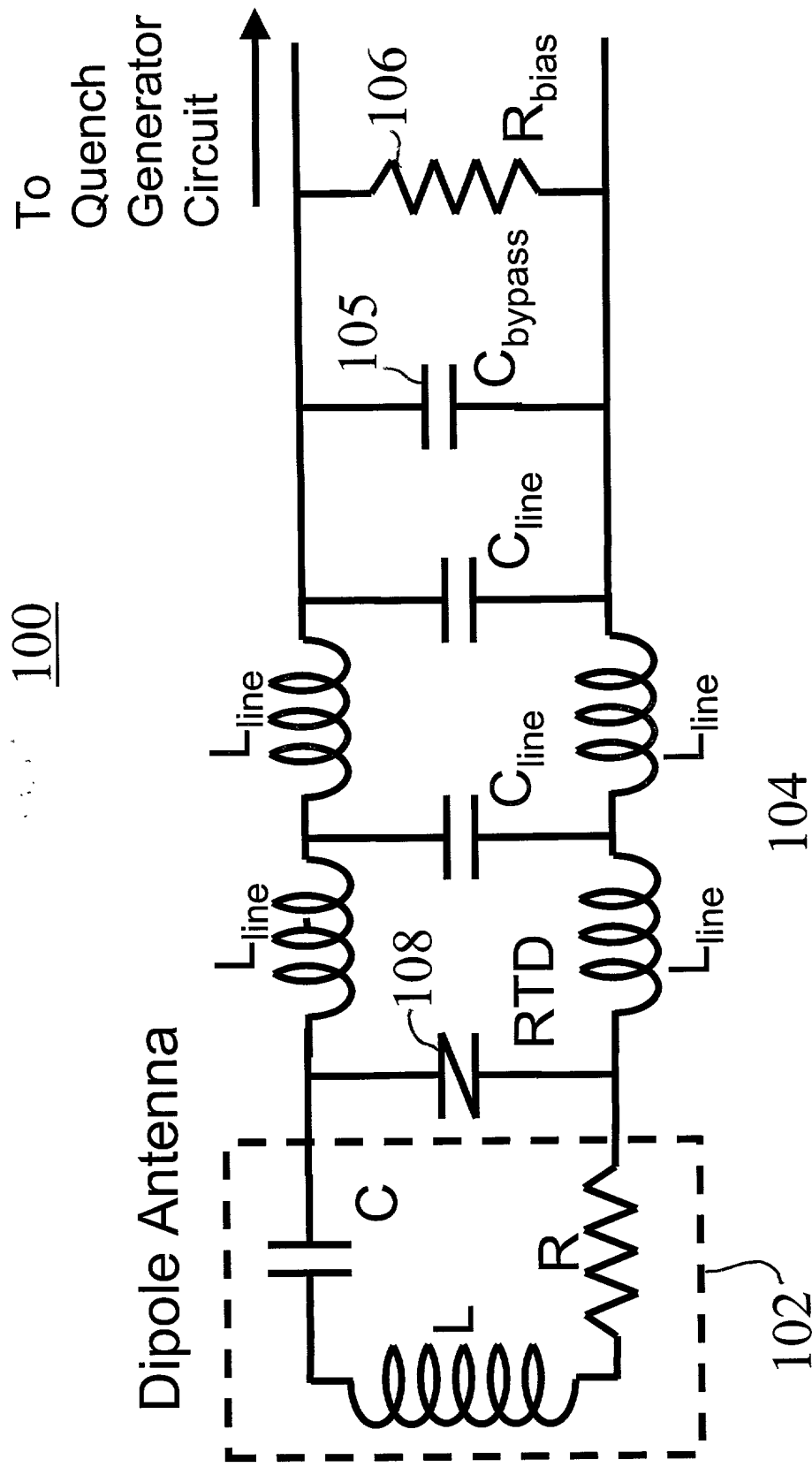


Figure 15

# Top View of RF Power Meter

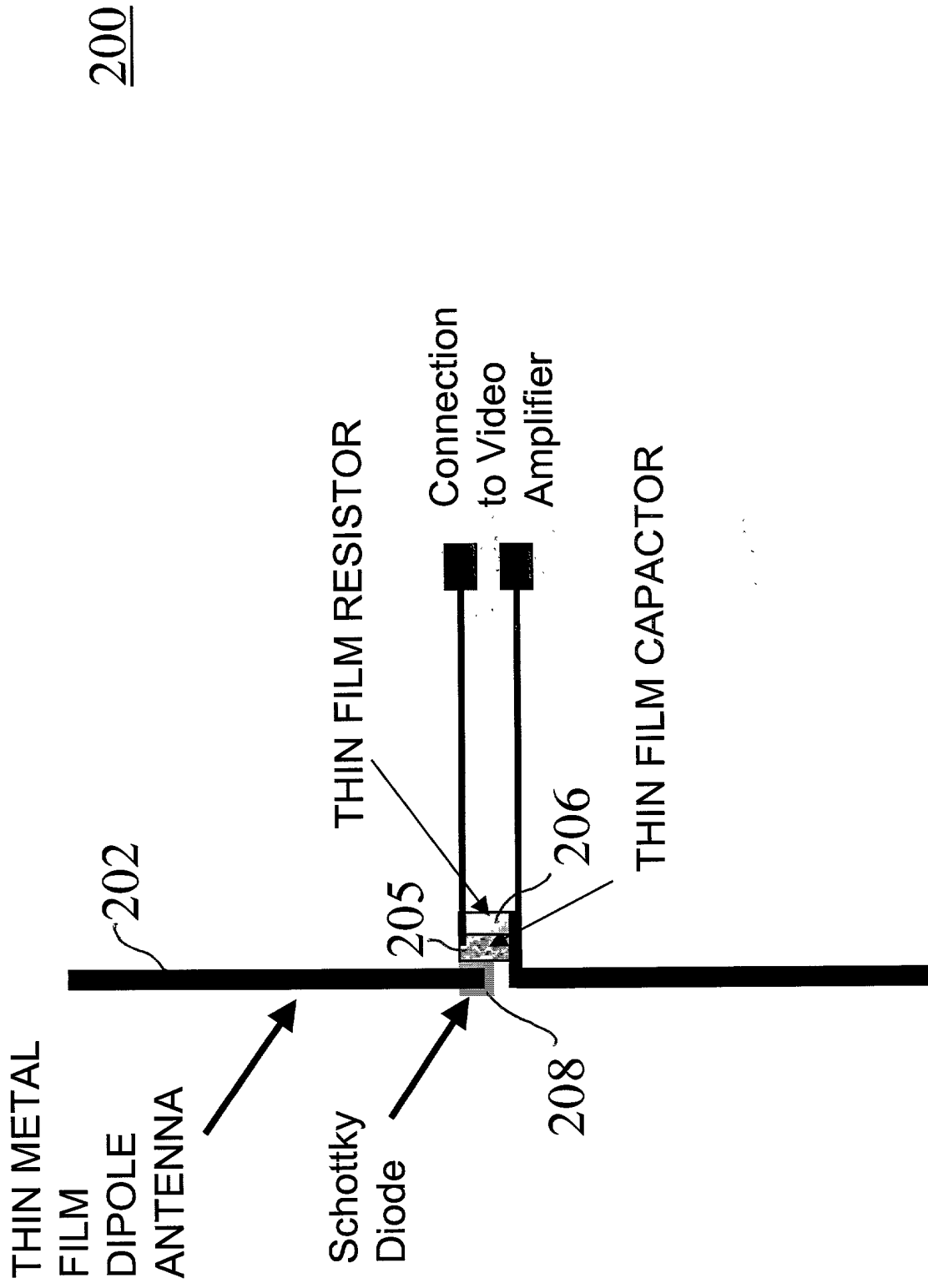


Figure 16

200

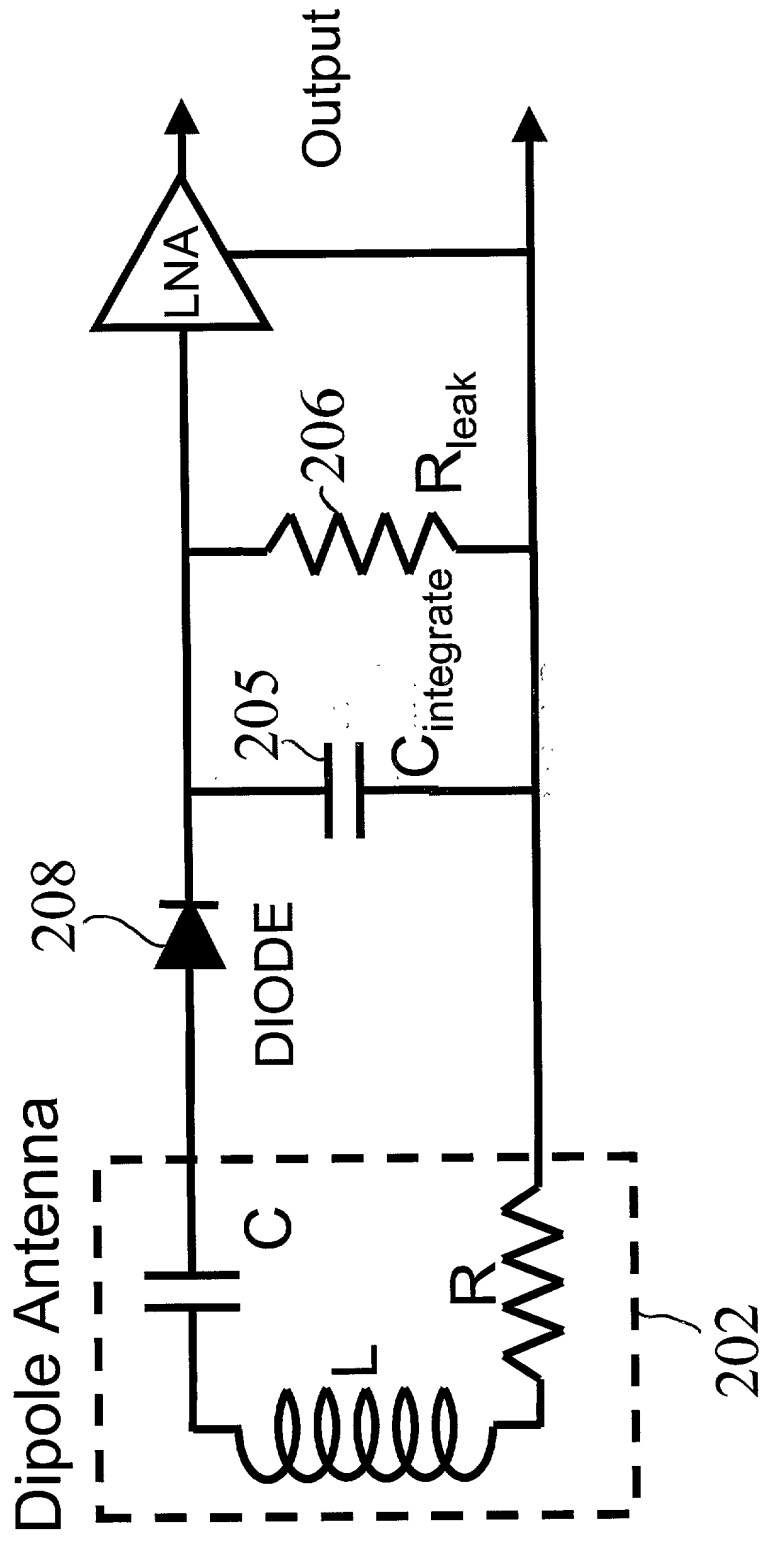
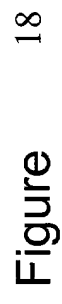


Figure 17



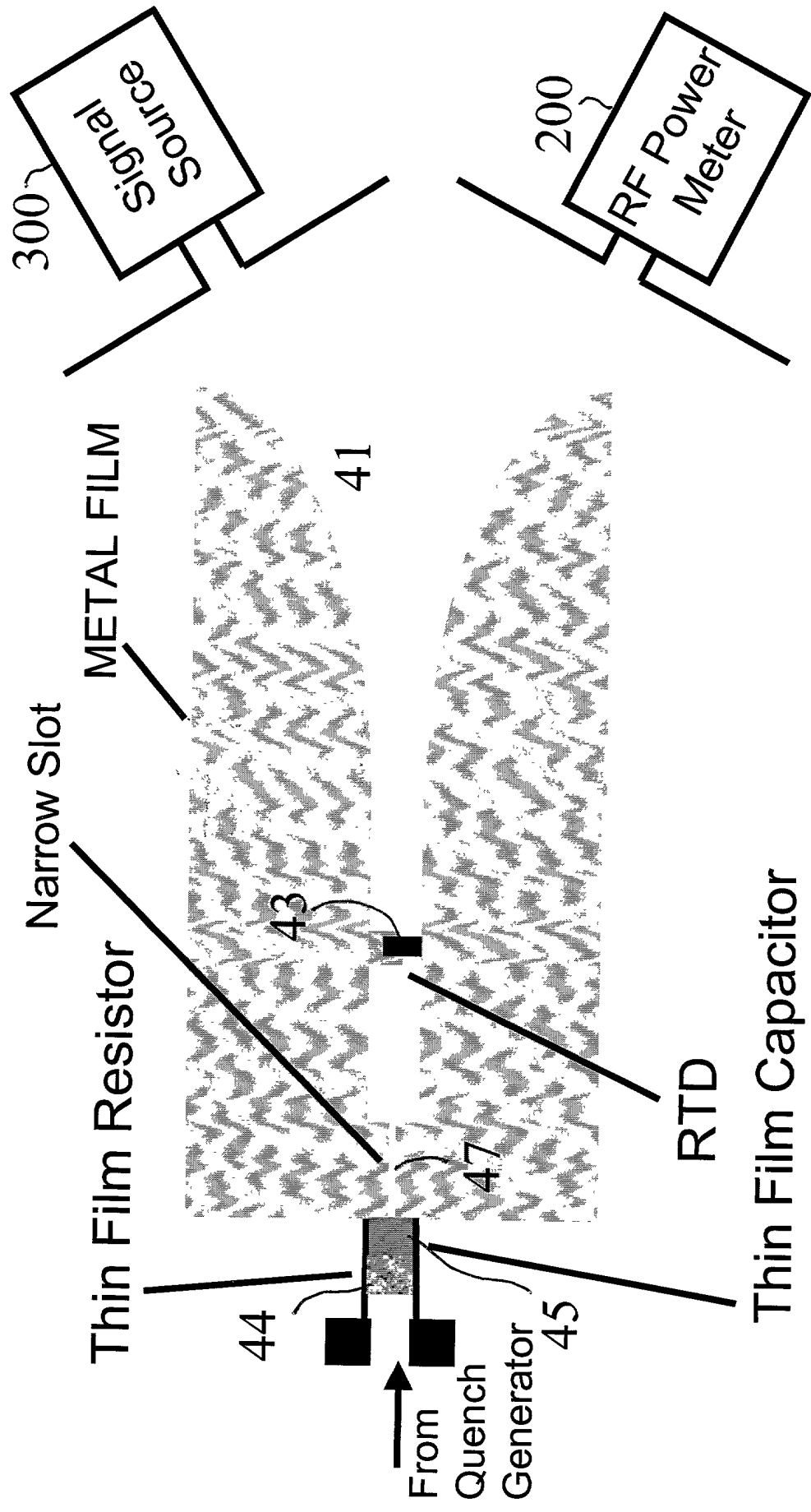


Figure 19

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As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled SUPER-REGENERATIVE MICROWAVE DETECTOR

the specification of which (check one):

  X   is attached hereto; or

       was filed on        as Application Serial No.        and

was amended on        (if applicable);

I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above; and

I acknowledge the duty to disclose to the U.S. Patent and Trademark Office all information known to me to be material to patentability as defined in 37 C.F.R. § 1.56.

I hereby claim foreign priority benefits under 35 U.S.C. § 119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application(s) for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

<u>Number</u>	<u>Country</u>	<u>Date Filed</u>	<u>Priority Claimed</u> (Yes) (No)
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None



I hereby claim the benefit under 35 U.S.C. § 119(e) of any United States provisional application(s) listed below:

<u>Application</u> <u>Serial Number</u>	<u>Date Filed</u>
--	-------------------

None

I hereby claim the benefit under 35 U.S.C. § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application(s) in the manner provided by the first paragraph of 35 U.S.C. § 112, I acknowledge the duty to disclose to the U.S. Patent and Trademark Office all information known to me to be material to patentability as defined in 37 C.F.R. § 1.56 which became available between the filing date of the prior application(s) and the national or PCT international filing date of this application:

<u>Application</u> <u>Serial Number</u>	<u>Date Filed</u>	<u>Status</u> (Patented, Pending, Abandoned)
None		

I hereby appoint the following as my attorneys with full power of substitution and revocation, to prosecute this application and to transact all business in the United States Patent and Trademark Office connected therewith, and to file and prosecute any international patent applications filed thereon before any international authorities:

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Reg. No. 30,222  
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Reg. No. 45,152  
Reg. No. 43,596  
Reg. No. 45,460  
Reg. No. 45,691  
Reg. No. 45,560

all of the firm of Baker Botts L.L.P.

Send Correspondence To:

Jerry W. Mills  
Baker Botts L.L.P.  
2001 Ross Avenue  
Dallas, Texas 75201-2980

Direct Telephone Calls To:

Robert L. Troike  
at (202) 639-7710  
Atty. Docket No. 004578.1111

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Full name of the sole inventor

Gary Frazier

Inventor's signature

Gary Frazier

Date

20 NOVEMBER 2000

Residence (City, County, State)

Garland, Dallas County, Texas

Citizenship

United States of America

Post Office Address

106 E. Apollo Road  
Garland, Dallas County, Texas

004578.1106